Product data sheet

1. General description

Dual common cathode power Schottky diode in TO263 (D2PAK) package.





2. Features and benefits

- High junction temperature up to 150 °C
- · High efficiency
- · Low forward voltage drop, negligible switching losses

3. Applications

- · DC to DC converters
- · Freewheeling diode
- · OR-ing diode
- · Switched mode power supply rectifier

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values		Unit			
Absolute maximum rating									
V_{RRM}	repetitive peak reverse voltage			100		V			
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 134 °C; per diode; Fig. 1; Fig. 2; Fig. 3		20 A		A			
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; $T_{mb} \le$ 131 °C; both diodes conducting		40 A		A			
Symbol	Parameter	Conditions	Notes	Min Typ Max		Unit			
Static cha	aracteristics								
V_{F}	forward voltage	I _F = 10 A; T _j = 25 °C; prediode; <u>Fig. 6</u>		-	0.54	0.59	V		
		$I_F = 10 \text{ A}$; $T_j = 125 \text{ °C}$; prediode; Fig. 6		-	0.5	0.56	V		
		I _F = 20 A; T _j = 25 °C; prediode; <u>Fig. 6</u>		-	0.67	0.71	V		
		I _F = 20 A; T _j = 125 °C; prediode; <u>Fig. 6</u>		-	0.63	0.68	V		
I _R reverse current		$V_R = 100 \text{ V}; T_j = 25 \text{ °C}; \text{ prediode}; Fig. 7$		-	15	50	μA		
		$V_R = 100 \text{ V}; T_j = 125 \text{ °C}; \text{ prediode}; Fig. 7$		-	13	-	mA		

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A	anode 1		
2	K	cathode		A1 A2
3	А	anode 2		K sym125
mb	mb	mounting base; connected to cathode	1 3	Symile

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WN3S40H100CB	TO263	WN3S40H100CBJ	Reel	800	TO263d	17-Mar-2023

7. Marking

Table 4. Marking codes

Type number	Marking codes
WN3S40H100CB	WN3S40H 100CB

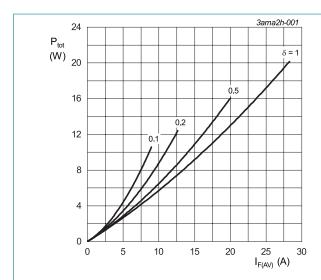
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

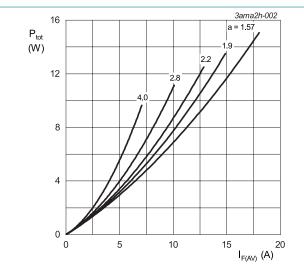
Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			100	V
V_{RWM}	crest working reverse voltage			100	V
V_R	reverse voltage	DC		100	V
I _{F(AV)}	average forward current	$δ$ = 0.5 ; square-wave pulse; $T_{mb} \le 134$ °C; per diode; Fig. 1; Fig. 2; Fig. 3		20	Α
$I_{O(AV)}$	average output current	δ = 0.5 ; square-wave pulse; $T_{mb} \le 131$ °C; both diodes conducting		40	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4		380	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		418	А
T _{stg}	storage temperature			-40 to 150	°C
T _j	junction temperature		[1]	-40 to 150	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$



 $\begin{aligned} &I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta} \\ &V_o = 0.496 \text{ V}; \text{ R}_s = 0.0077 \text{ }\Omega \end{aligned}$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}$ / $I_{F(AV)}$ V_o = 0.496 V; R_s = 0.0077 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values; per diode

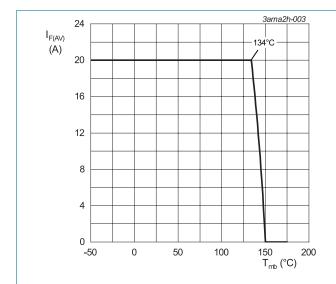


Fig. 3. Average forward current as a function of mounting base temperature; maximum values; per diode

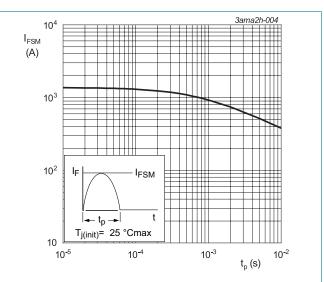


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values; per diode

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance	per diode; Fig. 5	-	-	1	K/W
	from junction to mounting base	both diodes conducting	-	-	0.6	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

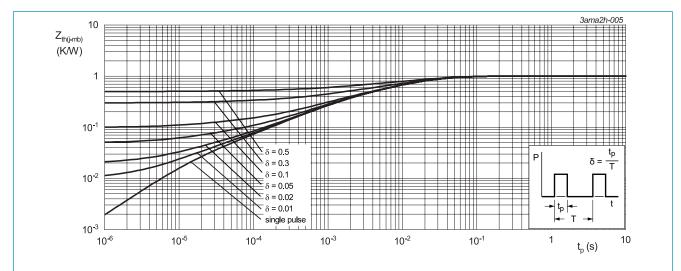
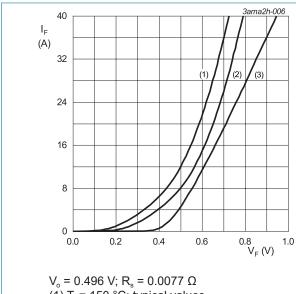


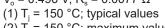
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values; per diode

10. Characteristics

Table 7. Characteristics

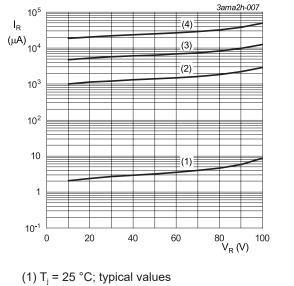
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static cha	Static characteristics							
V _F forward voltage		$I_F = 20 \text{ A}; T_j = 25 \text{ °C}; \text{ prediode}; \frac{\text{Fig. 6}}{\text{C}}$		-	0.67	0.71	V	
		I _F = 20 A; T _j = 125 °C; prediode		-	0.63	-	V	
		I _F = 20 A; T _j = 150 °C; prediode; <u>Fig. 6</u>		-	0.59	0.65	V	
		I _F = 10 A; T _j = 25 °C; prediode; <u>Fig. 6</u>		-	0.54	0.59	V	
		I _F = 10 A; T _j = 125 °C; prediode		-	0.50	-	V	
I _R reverse current		$V_R = 100 \text{ V}; T_j = 25 \text{ °C}; \text{ prediode}; \underline{\text{Fig. 7}}$		-	15	50	μA	
		V _R = 100 V; T _j = 125 °C; prediode; <u>Fig. 7</u>		-	13	-	mA	





(2) $T_j = 150$ °C; maximum values (3) $T_i = 25$ °C; maximum values

Fig. 6. Forward current as a function of forward voltage; per diode

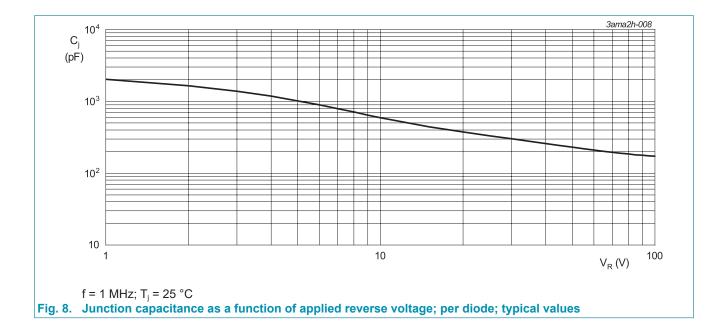


(2) T_i = 100 °C; typical values

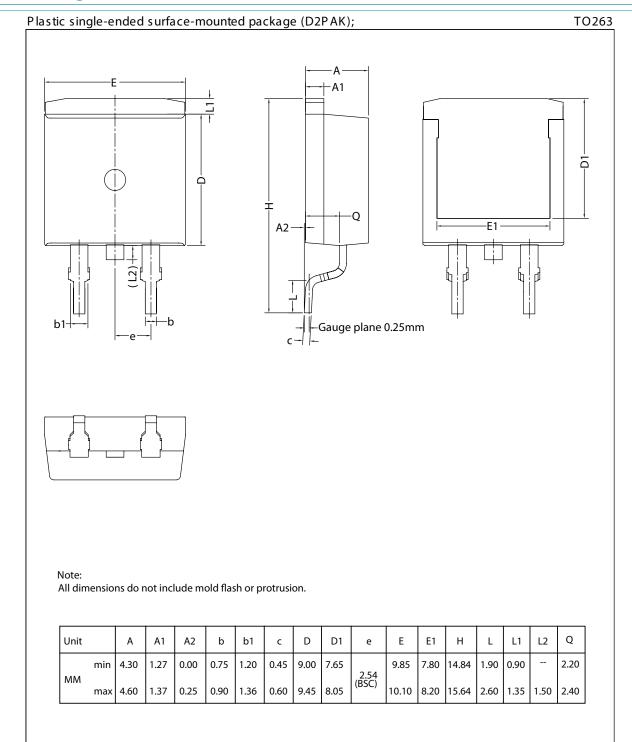
(3) T_i = 125 °C; typical values

(4) T_i = 150 °C; typical values

Fig. 7. Reverse leakage current as a function of reverse voltage; per diode; typical value



11. Package outline



12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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